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20A, 100V - 200V Trench Schottky Rectifiers

FEATURES

- Patented Trench Schottky technology
- Excellent high temperature stability
- Low forward voltage
- Low power loss/ high efficiency
- High forward surge capability
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

TYPICAL APPLICATIONS

Trench Schottky barrier rectifier is designed for high frequency switched mode power supplies such as adapters, lighting, and DC/DC converters.

MECHANICAL DATA

Case: I²PAK

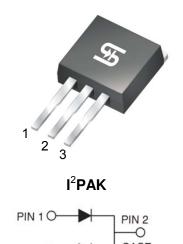
Molding compound meets UL 94 V-0 flammability rating

Packing code with suffix "G" means green compound (halogen-free) **Terminal:** Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 1A whisker test

Polarity: As marked

Weight: 1.6 g (approximately)







PARAMETER Maximum repetitive peak reverse voltage		SYMBOL		20H CW	TSI:	_		20H CW		20H CW	UNIT	
		V_{RRM}	10	00	12	20	15	50	20	00	V	
Maximum average forward rectified	per device		ı	20						۸		
current	per	r diode	I _{F(AV)}	10						A		
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load per diode			I _{FSM}	150					А			
Voltage rate of change (Rated V _R)			dV/dt	10000					V/µs			
				TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	
	I _F = 5A	T _{.l} = 25°C	V	0.57	-	0.62	-	0.72	-	0.77	-	- V
Instantaneous forward voltage per diode		10A		0.67	0.79	0.78	0.87	0.81	0.90	0.83	0.93	
(Note1)	I _F = 5A	T _{.I} = 125°C	- V _F	0.50	-	0.53	-	0.58	-	0.62	-	
	I _F = 10A	1 _J = 125 C		0.59	0.68	0.63	0.72	0.66	0.75	0.68	0.78	
Instantaneous reverse current per diode		T _J = 25°C	I _R	-	200	_	200	-	100	-	100	μΑ
at rated reverse voltage	Ī	T _J = 125°C		8	25	8	25	3	15	3	15	mA
Touris all the agreed resistance are adicate		$R_{ heta JC}$	2.8						°C/W			
Typical thermal resistance per diode			$R_{\theta JL}$	3.8						°C/W		
Operating junction temperature range			TJ	- 55 to +150					°C			
Storage temperature range			T _{STG}	- 55 to +150					°C			

Note 1: Pulse test with pulse width = 300µs, 1% duty cycle

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ORDERING INFORMATION							
PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING			
TSI20HXXXCW (Note 1, 2)	CO	G	I ² PAK	50 / Tube			

Note 1: "XXX" defines voltage from 100V (TSI20H100CW) to 200V (TSI20H200CW)

Note 2: Whole series with green compound

EXAMPLE						
PREFERRED P/N	PREFERRED P/N PART NO.		PACKING CODE SUFFIX	DESCRIPTION		
TSI20H120CW C0G	TSI20H120CW	C0	G	Green compound		

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

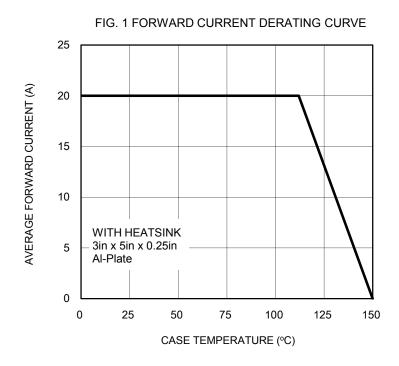
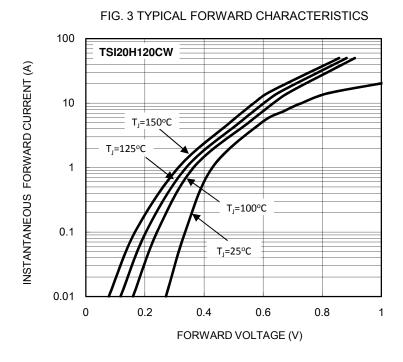


FIG. 2 TYPICAL FORWARD CHARACTERISTICS 100 TSI20H100CW INSTANTANEOUS FORWARD CURRENT (A) 10 T_J=125°C T_J=100°C 0.1 $T_J=25^{\circ}C$ 0.01 0.0 0.2 0.4 0.6 8.0 1.0 FORWARD VOLTAGE (V)



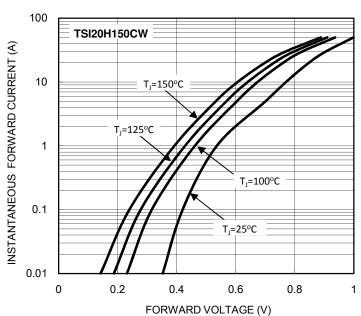


FIG. 4 TYPICAL FORWARD CHARACTERISTICS

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FIG. 5 TYPICAL FORWARD CHARACTERISTICS

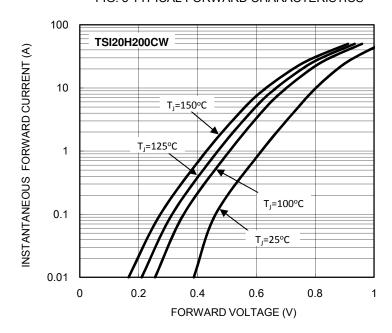


FIG. 6 TYPICAL REVERSE CHARACTERISTICS

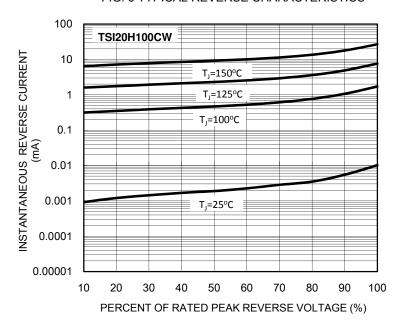


FIG. 7 TYPICAL REVERSE CHARACTERISTICS

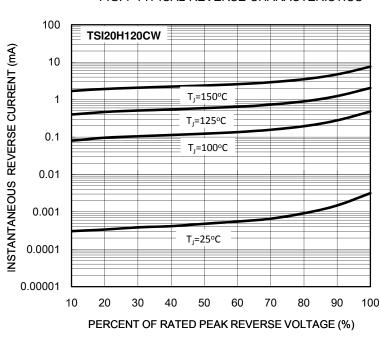


FIG. 8 TYPICAL REVERSE CHARACTERISTICS

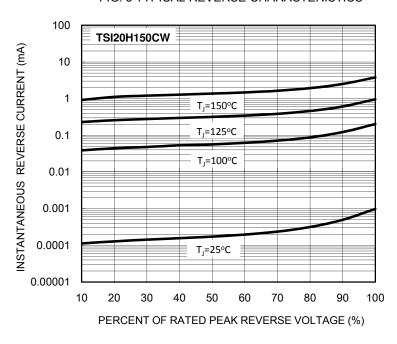


FIG. 9 TYPICAL REVERSE CHARACTERISTICS

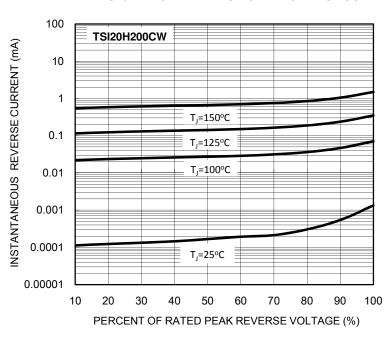
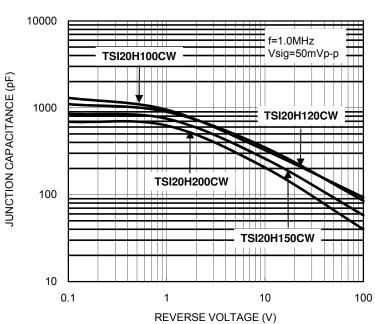


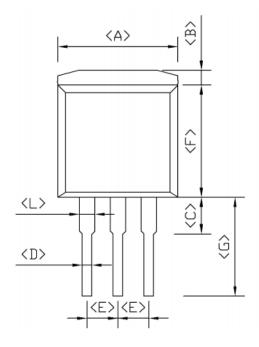
FIG. 10 TYPICAL JUNCTION CAPACITANCE

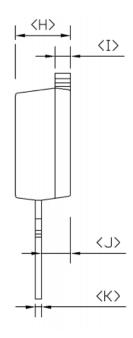




PACKAGE OUTLINE DIMENSIONS

I²PAK





DIM.	Unit	(mm)	Unit (inch)			
DIIVI.	Min	Max	Min	Max		
Α	-	10.50	-	0.413		
В	1.14	1.40	0.045	0.055		
С	2.80	4.20	0.110	0.165		
D	0.68	0.94	0.027	0.037		
E	2.41	2.67	0.095	0.105		
F	9.07	9.47	0.357	0.373		
G	7.79	9.35	0.307	0.368		
Н	4.40	4.70	0.173	0.185		
ı	1.14	1.40	0.045	0.055		
J	2.20	2.80	0.087	0.110		
K	0.35	0.64	0.014	0.025		
L	0.95	1.45	0.037	0.057		

MARKING DIAGRAM



P/N = Marking Code G = Green Compound

YWW = Date Code F = Factory Code

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